Postdoctoral Fellow Position: CMOS / GAN NMR BASED DEEP SUBSURFACE IMAGING AND OIL EXPLORATION

Position

Title	Postdoctoral Fellow Position: CMOS / GAN NMR BASED DEEP SUBSURFACE IMAGING AND OIL EXPLORATION
School	Harvard John A. Paulson School of Engineering and Applied Sciences
Department/Area	
Position Description	Two post doc positions are open with the expertise required in CMOS or GaN integrated circuit design, for applications in NMR-based deep subsurface imaging and oil exploration. Interested applicants please send CV and names of at least 2 references to donhee@seas.harvard.edu.
Basic Qualifications	PhD training in one of the following broadly defined areas: 1) CMOS integrated circuits; 2) electrochemistry; 3) nano- and micro-fabrications; 4) bio-electronics.
Additional Qualifications	
Special Instructions	
Contact Information	Donhee Ham
Contact Email	donhee@seas.harvard.edu
Equal Opportunity Employer	We are an equal opportunity employer and all qualified applicants will receive consideration for employment without regard to race, color, religion, sex, national origin, disability status, protected veteran status, gender identity, sexual orientation, pregnancy and pregnancy-related conditions or any other characteristic protected by law.
Minimum Number of References Required	
Maximum Number of References Allowed	

Supplemental Questions

Required fields are indicated with an asterisk (*).

Applicant Documents

Required Documents

Optional Documents